

N-channel 100V 16 mΩ standard level MOSFET in TO-220 Rev. 3 — 27 September 2011 Product data

Product data sheet

Product profile 1.

1.1 General description

Standard level N-channel MOSFET in a TO220 packages qualified to 175C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive

1.3 Applications

- DC-to-DC converters
- Load switching

- Motor control
- Server power supplies

1.4 Quick reference data

Table 1. **Quick reference data**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	-	100	V
I _D	drain current	$T_j = 25 \text{ °C}; V_{GS} = 10 \text{ V};$ see Figure 1	-	-	57	A
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	-	148	W
Tj	junction temperature		-55	-	175	°C
Static ch	aracteristics					
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 15 A; T_j = 100 °C; see <u>Figure 12</u>	-	-	28.8	mΩ
		V_{GS} = 10 V; I_D = 15 A; T_j = 25 °C; see <u>Figure 13</u>	-	13	16	mΩ
Dynamic	characteristics					
Q_{GD}	gate-drain charge	V_{GS} = 10 V; I _D = 30 A; V _{DS} = 50 V;	-	15	-	nC
Q _{G(tot)}	total gate charge	see Figure 14; see Figure 15	-	49	-	nC
Avalanch	ne ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy		-	-	101	mJ

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Pinning information 2.

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		-
2	D	drain	mb	
3	S	source		
	S	source		
mb	D	mounting base; connected to drain		mbb076 S

SOT78 (TO-220AB)

Ordering information 3.

Table 3. **Ordering information**

Type number	Package	Package			
	Name	Description	Version		
PSMN016-100PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78		

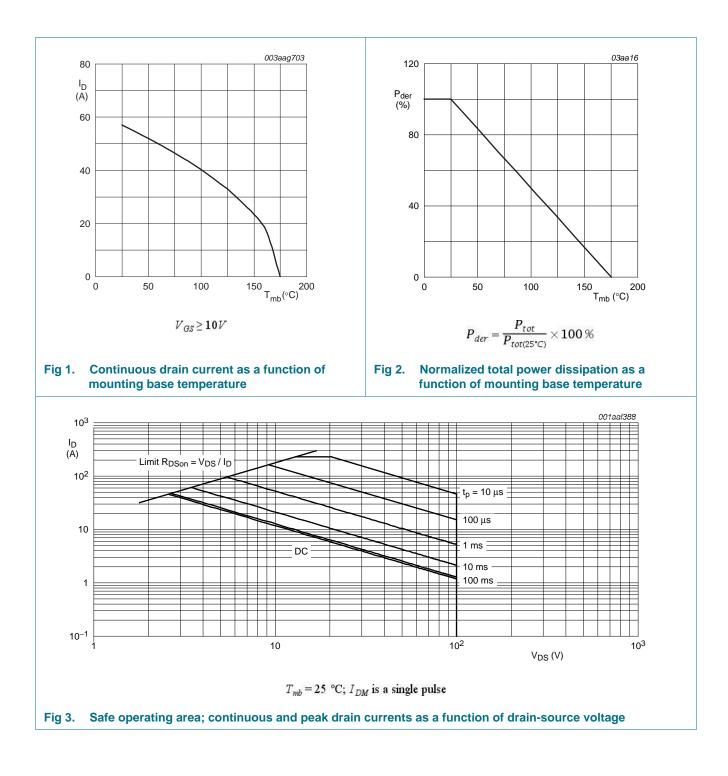
Limiting values 4.

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	100	V
V _{DGR}	drain-gate voltage	T _j ≤ 175 °C; T _j ≥ 25 °C; R _{GS} = 20 kΩ	-	100	V
V _{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 100 °C; see <u>Figure 1</u>	-	40	А
		V_{GS} = 10 V; T_j = 25 °C; see <u>Figure 1</u>	-	57	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; see Figure 3	-	230	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	148	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
Source-dr	ain diode				
I _S	source current	T _{mb} = 25 °C	-	57	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	230	А
Avalanche	e ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$ V_{GS} = 10 \text{ V}; \text{T}_{j(\text{init})} = 25 \text{ °C}; \text{I}_{\text{D}} = 60 \text{ A}; \\ V_{\text{sup}} \leq 100 \text{ V}; \text{ unclamped}; \text{R}_{\text{GS}} = 50 \Omega $	-	101	mJ
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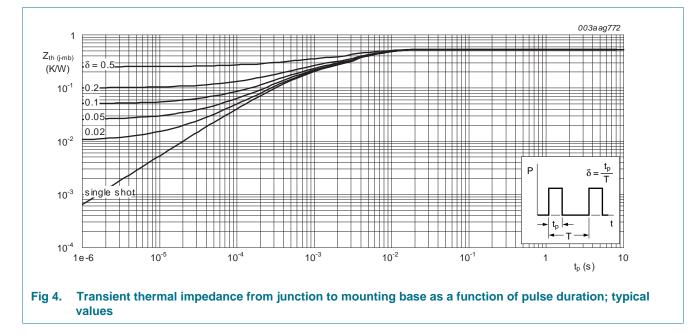
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5. Thermal characteristics

Table 5. Thermal	characteristics
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	see Figure 4	-	0.56	1.01	K/W
R _{th(j-a)}	thermal resistance from junction to ambient		<u>[1]</u> -	50	-	K/W

[1] minimum footprint; mounted on a printed-circuit board to ambient



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6. Characteristics

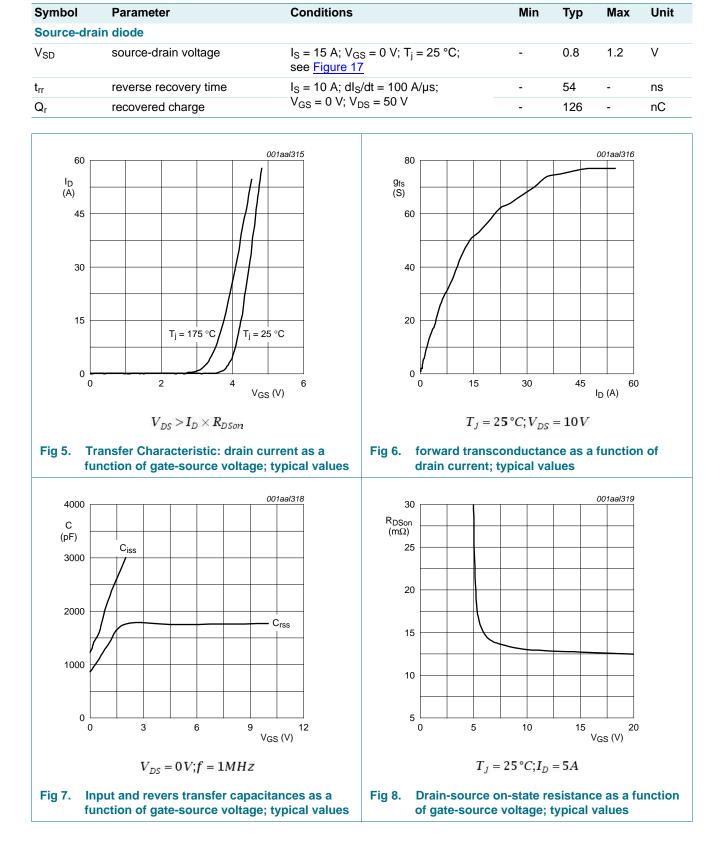
Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = -55 \text{ °C}$	90	-	-	V
		$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{V}; T_j = 25 ^\circ\text{C}$	100	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ see <u>Figure 10</u>	1	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 11</u> ; see <u>Figure 10</u>	2	3	4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ see Figure 10	-	-	4.8	V
I _{DSS}	drain leakage current	V_{DS} = 100 V; V_{GS} = 0 V; T_j = 125 °C	-	-	100	μA
		$V_{DS} = 100 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	0.05	5	μA
I _{GSS}	gate leakage current	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	10	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 15 A; T _j = 100 °C; see <u>Figure 12</u>	-	-	28.8	mΩ
		V _{GS} = 10 V; I _D = 15 A; T _j = 175 °C; see <u>Figure 12</u>	-	36.4	44.8	mΩ
		V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; see <u>Figure 13</u>	-	13	16	mΩ
R _G	internal gate resistance (AC)	f = 1 MHz	-	0.9	-	Ω
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$I_D = 0 A$; $V_{DS} = 0 V$; $V_{GS} = 10 V$; see Figure 14	-	40	-	nC
		$I_D = 30 \text{ A}; V_{DS} = 50 \text{ V}; V_{GS} = 10 \text{ V};$	-	49	-	nC
Q _{GS}	gate-source charge	see Figure 14; see Figure 15	-	12	-	nC
Q _{GS(th)}	pre-threshold gate-source charge	I_D = 30 A; V_{DS} = 50 V; V_{GS} = 10 V; see Figure 14	-	7.75	-	nC
Q _{GS(th-pl)}	post-threshold gate-source charge		-	4.25	-	nC
Q _{GD}	gate-drain charge	$I_D = 30 \text{ A}; V_{DS} = 50 \text{ V}; V_{GS} = 10 \text{ V};$ see Figure 14; see Figure 15	-	15	-	nC
V _{GS(pl)}	gate-source plateau voltage	V _{DS} = 50 V; see <u>Figure 14;</u> see <u>Figure 15</u>	-	4.5	-	V
C _{iss}	input capacitance	$V_{DS} = 50 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$	-	2404	-	pF
C _{oss}	output capacitance	T _j = 25 °C; see <u>Figure 16</u>	-	189	-	pF
C _{rss}	reverse transfer capacitance		-	113	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 50 \text{ V}; \text{ R}_{L} = 1.7 \Omega; \text{ V}_{GS} = 10 \text{ V};$	-	17	-	ns
t _r	rise time	$R_{G(ext)} = 4.7 \ \Omega; \ T_j = 25 \ ^{\circ}C$	-	23	-	ns
t _{d(off)}	turn-off delay time		-	36	-	ns
t _f	fall time		-	18	-	ns

Table 6.

Characteristics ... continued

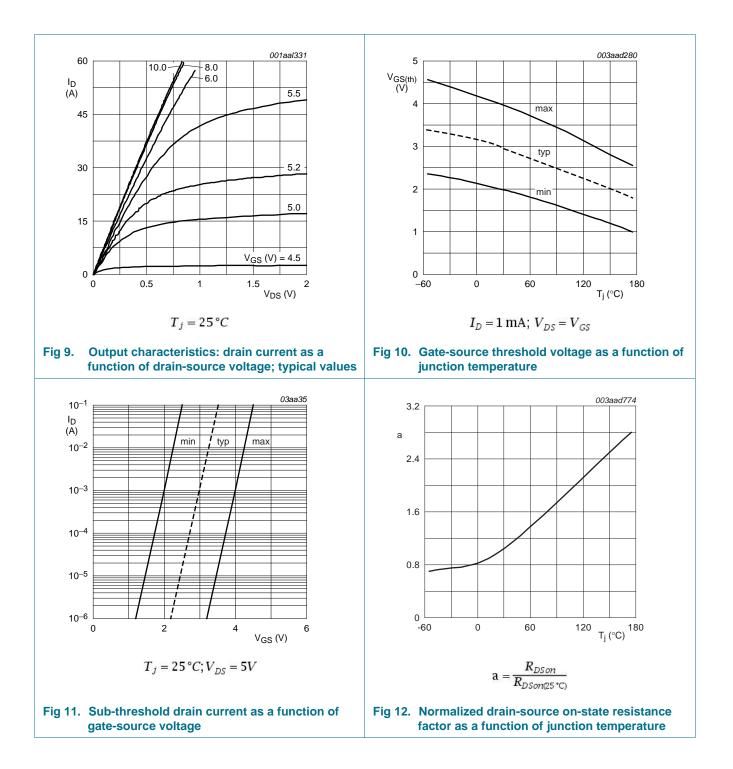
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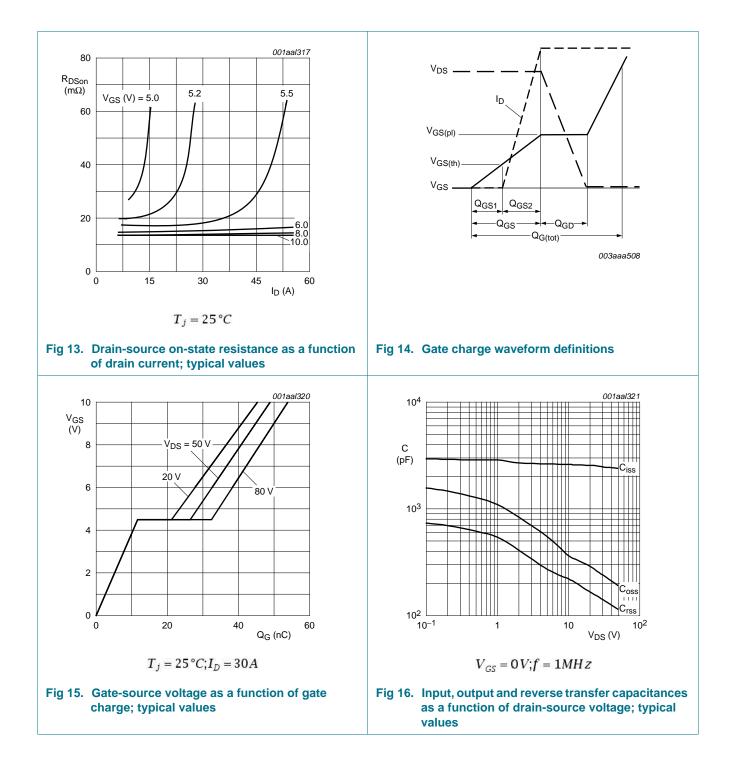


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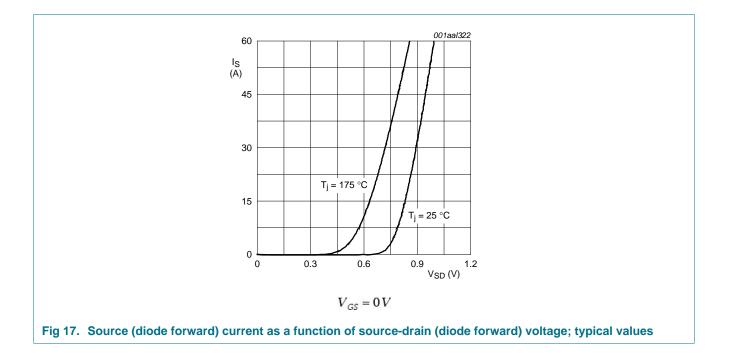
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Package outline 7.

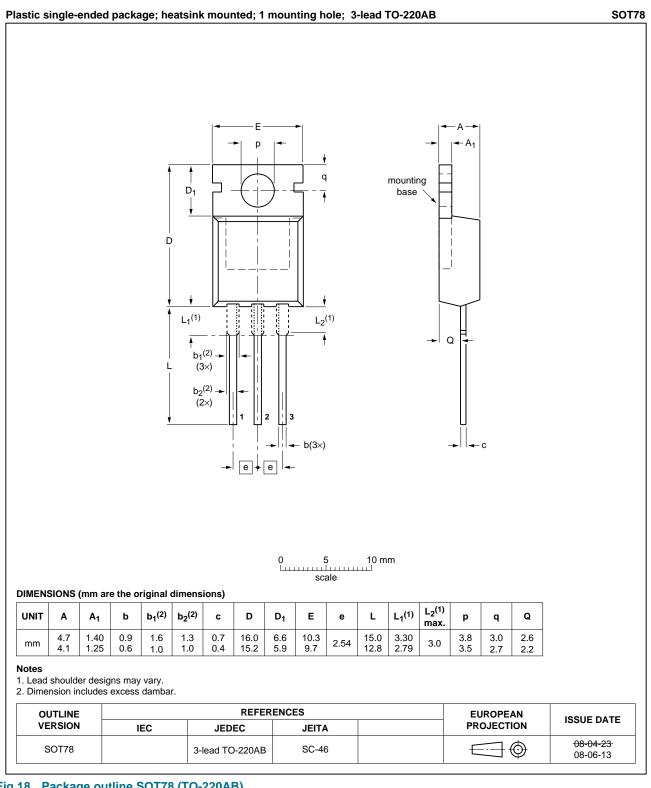


Fig 18. Package outline SOT78 (TO-220AB)

PSMN016-100PS **Product data sheet**

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8. Revision history

Table 7.	Revision	history
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Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN016-100PS v.3	20110927	Product data sheet	-	PSMN016-100PS v.2
Modifications:	 Various changes to 	o content.		
PSMN016-100PS v.2	20110721	Product data sheet	-	PSMN016-100PS v.1

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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